

Title (en)

MULTI-STAGE REFORMING PROCESS USING RHENIUM-CONTAINING CATALYST IN THE FINAL STAGE

Title (de)

VIELSTUFIGES REFORMIERVERFAHREN UNTER VERWENDUNG EINES RHENIUM ENTHALTENDEN KATALYSATORS IN DER ENDSTUFE

Title (fr)

PROCEDE DE REFORMAGE MULTIPHASE UTILISANT UN CATALYSEUR CONTENANT DU RHENIUM DANS LA PHASE FINALE

Publication

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Application

EP 00937606 A 20000518

Priority

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Abstract (en)

[origin: WO0071642A1] This is a process for upgrading a petroleum naphtha fraction. The naphtha is subjected to reforming and the reformatte is cascaded to a benzene and toluene synthesis zone over a benzene and toluene synthesis catalyst comprising a molecular sieve of low acid activity. The preferred molecular sieve is steamed ZSM-5. The benzene and toluene synthesis zone is operated under conditions compatible with the conditions of the reformer such as temperatures of above about 800 DEG F (427 DEG C). In one aspect of the invention, the benzene and toluene synthesis catalyst includes a metal hydrogenation component from group VII(B), specifically rhenium. In one mode of operation, the benzene and toluene synthesis catalyst replaces at least a portion of the catalyst in the reformer. The process produces a product containing an increased proportion of benzene, toluene, and/or xylenes, and a reduced portion of alkylated aromatics, as compared to reformatte.

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